

Product data sheet

1. General description

Planar passivated AC Thyristor Triac power switch in a SOT428 (DPAK) surface mountable plastic package with self-protective clamping capabilities against low and high energy transients.

2. Features and benefits

- Clamping structure ensuring safe high over-voltage withstand capability
- Direct interfacing with low power drivers and microcontrollers
- Full cycle AC conduction
- Over-voltage withstand capability to IEC 61000-4-5
- Pin compatible with standard triacs
- Planar passivated for voltage ruggedness and reliability
- Protective self turn-on capability for high energy transients
- Safe clamping capability for low energy over-voltage transients
- Sensitive gate for easy logic level triggering
- Surface mountable package
- Triggering in three quadrants only
- Very high immunity to false turn-on by dV/dt

3. Applications

- AC fan, pump and compressor controls
- Highly inductive, resistive and safety loads
- Large and small appliances (White Goods)
- Reversing induction motor controls

4. Quick reference data

Table 1. Quick reference data

	_			_		
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{DRM}	repetitive peak off- state voltage		-	-	800	V
I _{TSM}	non-repetitive peak on- state current	full sine wave; $T_{j(init)} = 25 \text{ °C};$ $t_p = 20 \text{ ms}; \text{ Fig. 4}; \text{ Fig. 5}$	-	-	35	A
Tj	junction temperature		-	-	125	°C
I _{T(RMS)}	RMS on-state current	full sine wave; T _{mb} ≤ 108 °C; <u>Fig. 1;</u> <u>Fig. 2; Fig. 3</u>	-	-	4	A





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Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{PP}	peak pulse voltage	T _j = 25 °C; non-repetitive, off-state; Fig. 6	-	-	2	kV
Static chara	acteristics	· · · ·		_		
I _{GT}	gate trigger current	V_D = 12 V; I _T = 100 mA; LD+ G+; T _j = 25 °C; Fig. 8	-	-	10	mA
		V_D = 12 V; I _T = 100 mA; LD+ G-; T _j = 25 °C; <u>Fig. 8</u>	-	-	10	mA
		V_D = 12 V; I _T = 100 mA; LD- G-; T _j = 25 °C; <u>Fig. 8</u>	-	-	10	mA
V _{CL}	clamping voltage	I _{CL} = 0.1 mA; t _p = 1 ms; T _j = 25 °C	850	-	-	V
Dynamic ch	narateristics	I	I			
dV _D /dt	rate of rise of off-state voltage	V_{DM} = 536 V; T _j = 125 °C; (V _{DM} = 67% of V _{DRM}); exponential waveform; gate open circuit; Fig. 13	500	-	-	V/µs
dI _{com} /dt	rate of change of commutating current	$V_D = 400 \text{ V}; \text{T}_\text{j} = 125 \text{ °C}; \text{I}_\text{T(RMS)} = 4 \text{ A};$ $dV_\text{com}/dt = 1 \text{ V}/\mu\text{s}; \text{ gate open circuit};$ $Fig. 14; Fig. 15$	8	-	-	A/ms

5. Pinning information

Table 2.	Pinning	information		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	СМ	common	mb	LD
2	LD	load		
3	G	gate		СМ
mb	LD	mounting base; load	1 3 DPAK (SOT428)	003aaf296

6. Ordering information

Table 3. Ordering information								
Type number	Package							
	Name	Description	Version					
ACTT4S-800E	DPAK	plastic single-ended surface-mounted package (DPAK); 3 leads (one lead cropped)	SOT428					

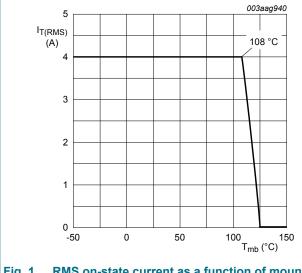
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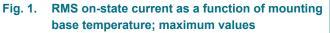
7. Limiting values

Table 4.Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Мах	Unit
V _{DRM}	repetitive peak off-state voltage		-	800	V
I _{T(RMS)}	RMS on-state current	full sine wave; T _{mb} ≤ 108 °C; <u>Fig. 1;</u> <u>Fig. 2; Fig. 3</u>	-	4	A
I _{TSM}	non-repetitive peak on-state current	full sine wave; $T_{j(init)} = 25 \text{ °C};$ $t_p = 20 \text{ ms}; \text{Fig. 4}; \text{Fig. 5}$	-	35	A
		full sine wave; $T_{j(init)} = 25 \text{ °C};$ $t_p = 16.7 \text{ ms}$	-	39	A
l ² t	I ² t for fusing	t _p = 10 ms; sine-wave pulse	-	6	A ² s
dl _T /dt	rate of rise of on-state current	I_T = 6 A; I_G = 0.2 A; dI_G/dt = 0.2 A/µs	-	100	A/µs
I _{GM}	peak gate current	t = 20 μs	-	2	А
P _{GM}	peak gate power		-	5	W
P _{G(AV)}	average gate power	over any 20 ms period	-	0.5	W
T _{stg}	storage temperature		-40	150	°C
Tj	junction temperature		-	125	°C
V _{PP}	peak pulse voltage	T _j = 25 °C; non-repetitive, off-state; Fig. 6	-	2	kV





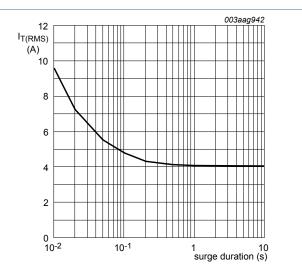
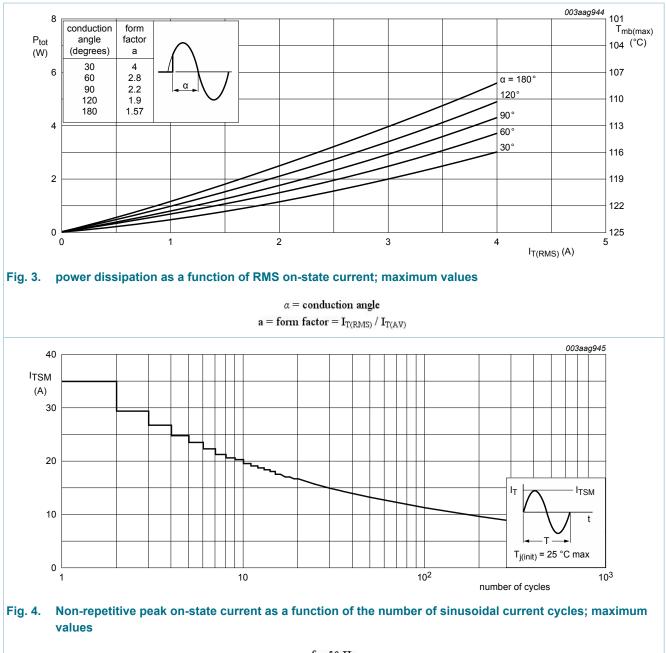


Fig. 2. RMS on-state current as a function of surge duration; maximum values

 $f = 50 \text{ Hz}; T_{mb} = 108 \text{ °C}$

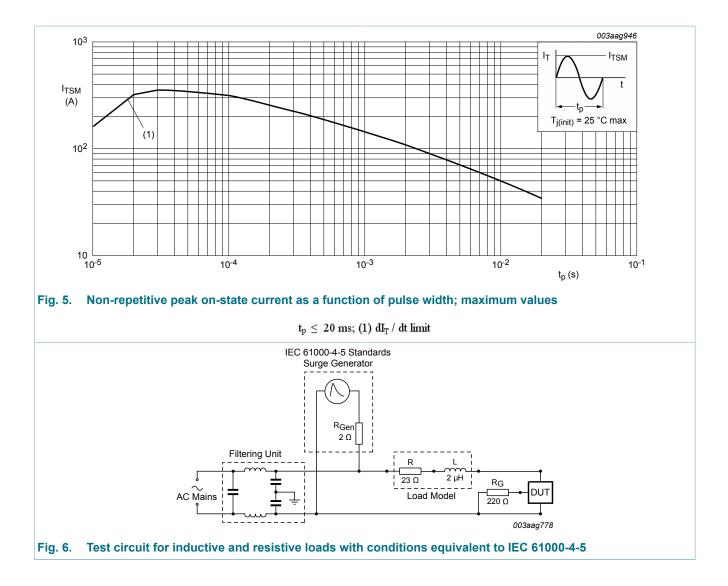
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f = 50 Hz

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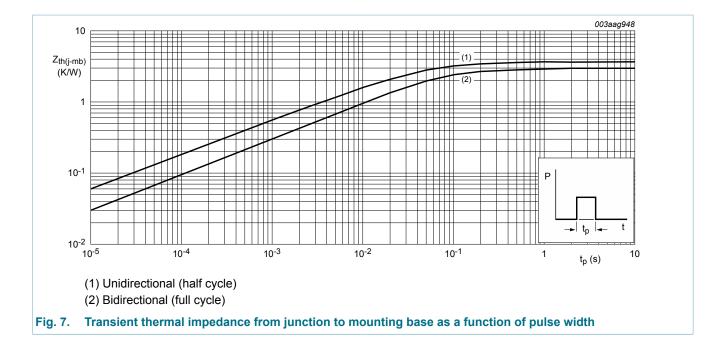
8. Thermal characteristics

Table 5.Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-mb)}	thermal resistance	full cycle; <u>Fig. 7</u>	-	-	3	K/W
	from junction to mounting base	half cycle; <u>Fig. 7</u>	-	-	3.7	K/W
R _{th(j-a)}	thermal resistance from junction to ambient	in free air	-	75	-	K/W

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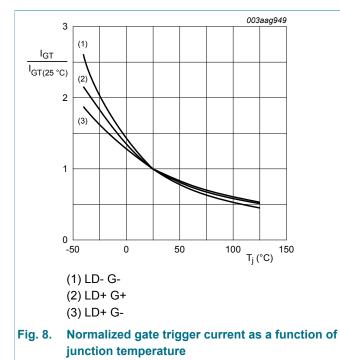
9. Characteristics

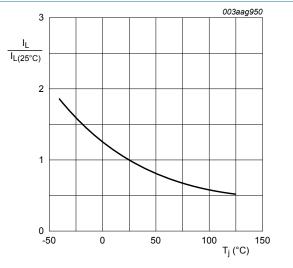
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static char	acteristics					
I _{GT}	gate trigger current	V _D = 12 V; I _T = 100 mA; LD+ G+; T _j = 25 °C; <u>Fig. 8</u>	-	-	10	mA
		V_D = 12 V; I _T = 100 mA; LD+ G-; T _j = 25 °C; Fig. 8	-	-	10	mA
		V _D = 12 V; I _T = 100 mA; LD- G-; T _j = 25 °C; <u>Fig. 8</u>	-	-	10	mA
IL	Iatching current	V_D = 12 V; I _G = 100 mA; LD+ G+; T _j = 25 °C; Fig. 9	-	-	30	mA
		V_D = 12 V; I _G = 100 mA; LD+ G-; T _j = 25 °C; Fig. 9	-	-	40	mA
		V_D = 12 V; I _G = 100 mA; LD- G-; T _j = 25 °C; Fig. 9	-	-	30	mA
I _H	holding current	V _D = 12 V; T _j = 25 °C; <u>Fig. 10</u>	-	-	20	mA
V _T	on-state voltage	I _T = 6 A; T _j = 25 °C; <u>Fig. 11</u>	-	-	1.7	V
V _{GT}	gate trigger voltage	V _D = 12 V; I _T = 100 mA; T _j = 25 °C; <u>Fig. 12</u>	-	0.8	1	V
		V _D = 400 V; I _T = 100 mA; T _j = 125 °C; <u>Fig. 12</u>	0.2	0.45	-	V
ID	off-state current	V _D = 800 V; T _i = 25 °C	-	-	10	μA

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Symbol	Parameter	Conditions	Min	Тур	Max	Unit
		V _D = 800 V; T _j = 125 °C	-	-	0.5	mA
V _{CL}	clamping voltage	I _{CL} = 0.1 mA; t _p = 1 ms; T _j = 25 °C	850	-	-	V
Dynamic cl	harateristics	1				
dV _D /dt	rate of rise of off-state voltage	V_{DM} = 536 V; T _j = 125 °C; (V _{DM} = 67% of V _{DRM}); exponential waveform; gate open circuit; Fig. 13	500	-	-	V/µs
dl _{com} /dt	rate of change of commutating current	$V_D = 400 \text{ V}; \text{T}_{\text{j}} = 125 \text{ °C}; \text{I}_{\text{T}(\text{RMS})} = 4 \text{ A};$ dV _{com} /dt = 20 V/µs; (snubberless condition); gate open circuit; <u>Fig. 14;</u> <u>Fig. 15</u>	4	-	-	A/ms
		$V_{D} = 400 \text{ V}; \text{T}_{\text{j}} = 125 \text{ °C}; \text{I}_{\text{T}(\text{RMS})} = 4 \text{ A};$ $dV_{\text{com}}/dt = 10 \text{ V}/\mu\text{s}; \text{ gate open circuit};$ $\overline{\text{Fig. 14}; \text{ Fig. 15}}$	5	-	-	A/ms
		$V_{D} = 400 \text{ V}; \text{T}_{\text{j}} = 125 \text{ °C}; \text{I}_{\text{T}(\text{RMS})} = 4 \text{ A};$ $dV_{\text{com}}/dt = 1 \text{ V}/\mu\text{s}; \text{ gate open circuit};$ $\overline{\text{Fig. 14; Fig. 15}}$	8	-	-	A/ms



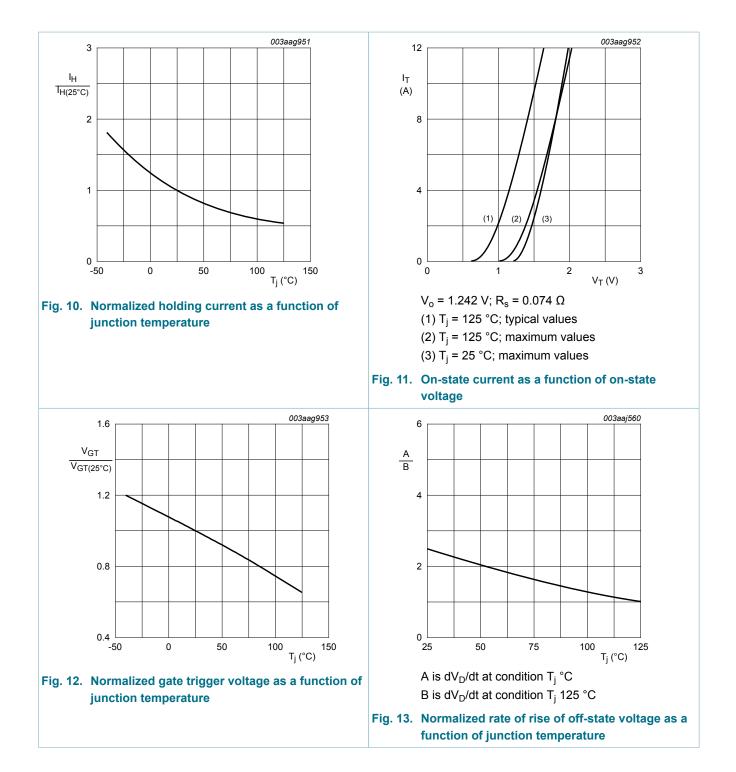






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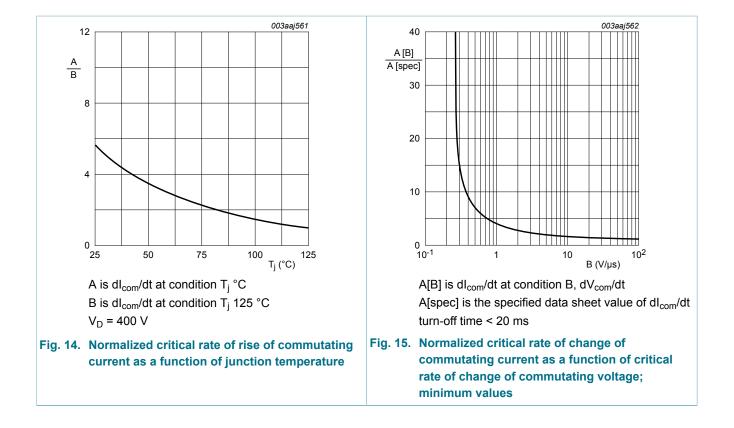


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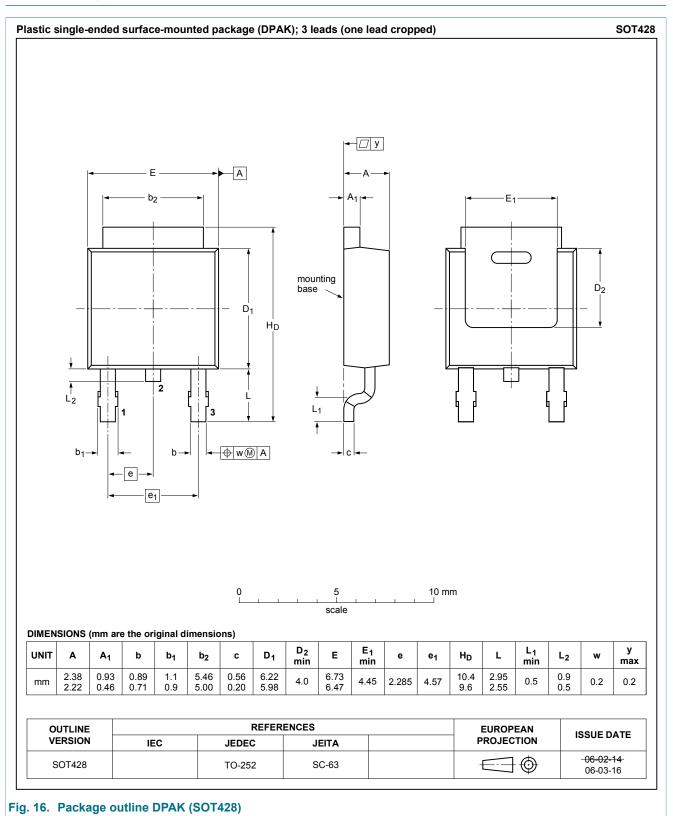
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10. Package outline

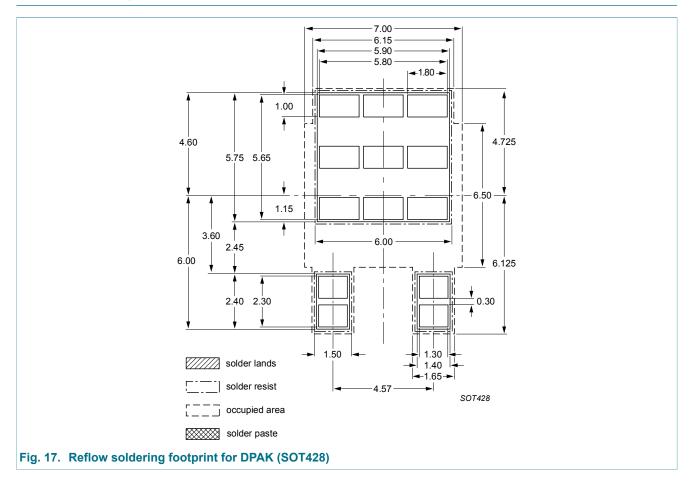


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11. Soldering



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12. Legal information

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Document status [1][2]	Product status [<u>3]</u>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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